Surface Mount Schottky Power Rectifier SMB Power Surface Mount Package

These devices employ the Schottky Barrier principle in a metal-to-silicon power rectifier. Features epitaxial construction with oxide passivation and metal overlay contact. Ideally suited for low voltage, high frequency switching power supplies; free wheeling diodes and polarity protection diodes.

Features

- Compact Package with J–Bend Leads Ideal for Automated Handling
- Highly Stable Oxide Passivated Junction
- Guardring for Over-Voltage Protection
- Low Forward Voltage Drop
- Pb–Free Packages are Available

Mechanical Characteristics

- Case: Molded Epoxy
- Epoxy Meets UL 94 V-0 @ 0.125 in
- Weight: 95 mg (approximately)
- Cathode Polarity Band
- Lead and Mounting Surface Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Available in 12 mm Tape, 2500 Units per 13 in Reel, Add "T3" Suffix to Part Number
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- ESD Ratings: Machine Model = C Human Body Model = 3B



ON Semiconductor®

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SCHOTTKY BARRIER RECTIFIER 2 AMPERES 20, 40 VOLTS

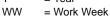


SMB CASE 403A PLASTIC

MARKING DIAGRAM



SS2x = Specific Device Code x = 2 or 4 A = Assembly Location Y = Year



= Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]
SS22T3	SMB	2500/Tape & Reel
SS22T3G	SMB (Pb–Free)	2500/Tape & Reel
SS24T3	SMB	2500/Tape & Reel
SS24T3G	SMB (Pb–Free)	2500/Tape & Reel

⁺For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage SS24	V _{RRM} V _{RWM} V _R	20 40	V
Average Rectified Forward Current (At Rated V_R , $T_L = 100^{\circ}C$)	Ι _Ο	2.0	A
Peak Repetitive Forward Current (At Rated V_R , Square Wave, 100 kHz, $T_C = 105^{\circ}C$)	I _{FRM}	3.0	A
Non-Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz)	I _{FSM}	75	A
Storage/Operating Case Temperature	T _{stg} , T _C	-55 to +150	°C
Operating Junction Temperature (Note 1)	TJ	-55 to +150	°C
Voltage Rate of Change (Rated V_R , $T_J = 25^{\circ}C$)	dv/dt	10,000	V/μs

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. The heat generated must be less than the thermal conductivity from Junction-to-Ambient: $dP_D/dT_J < 1/R_{\theta JA}$.

THERMAL CHARACTERISTICS

		1
		°C/W
$R_{\theta JL}$	24	
-		
$R_{\theta JA}$	80	
		00L

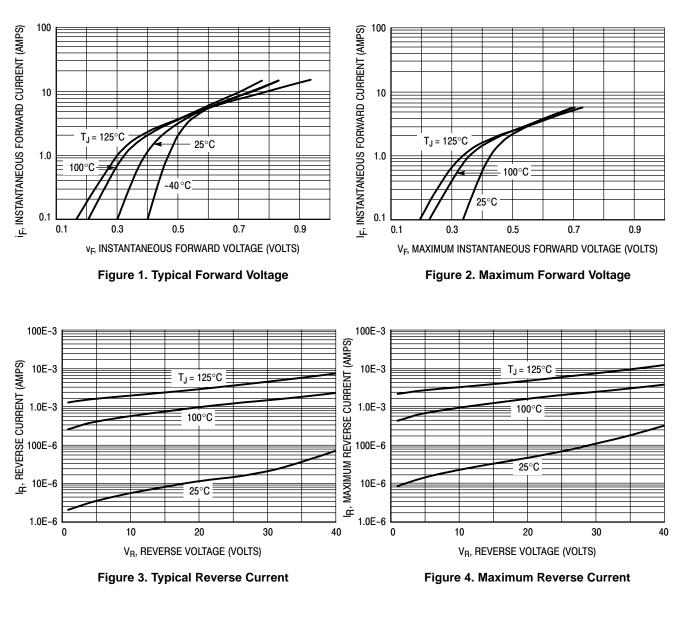
ELECTRICAL CHARACTERISTICS

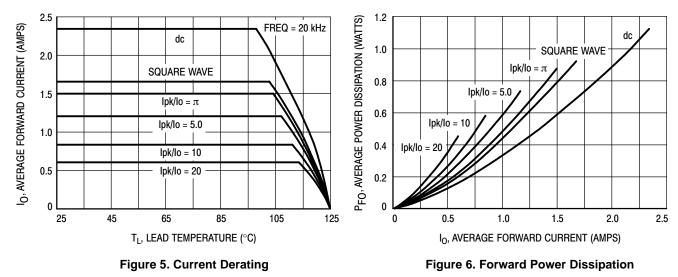
Maximum Instantaneous Forward Voltage (Note 4)		٧F	T _J = 25°C	T _J = 125°C	V
see Figure 2	(i _F = 2.0 A)		0.50	0.46	
Maximum Instantaneous Reverse Current (Note 4)		I _R	T _J = 25°C	T _J = 100°C	mA
see Figure 4	(V _R = 40 V)		0.4	5.7	

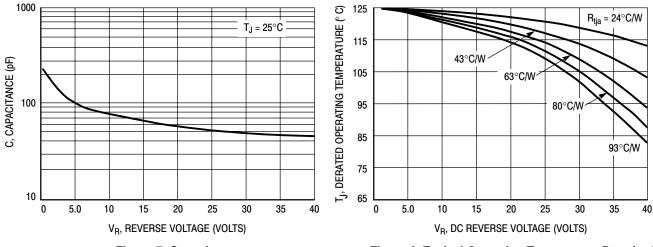
2. Mounted with minimum recommended pad size, PC Board FR4.

3. 1 inch square pad size (1 x 0.5 inch for each lead) on FR4 board.

4. Pulse Test: Pulse Width \leq 250 µs, Duty Cycle \leq 2.0%.











* Reverse power dissipation and the possibility of thermal runaway must be considered when operating this device under any reverse voltage conditions. Calculations of T_J therefore must include forward and reverse power effects. The allowable operating T_J may be calculated from the equation: $T_J = T_{Jmax} - r(t)(Pf + Pr)$ where

r(t) = thermal impedance under given conditions,

Pf = forward power dissipation, and

Pr = reverse power dissipation

This graph displays the derated allowable T_J due to reverse bias under DC conditions only and is calculated as $T_J = T_{Jmax} - r(t)Pr$, where r(t) = Rthja. For other power applications further calculations must be performed.

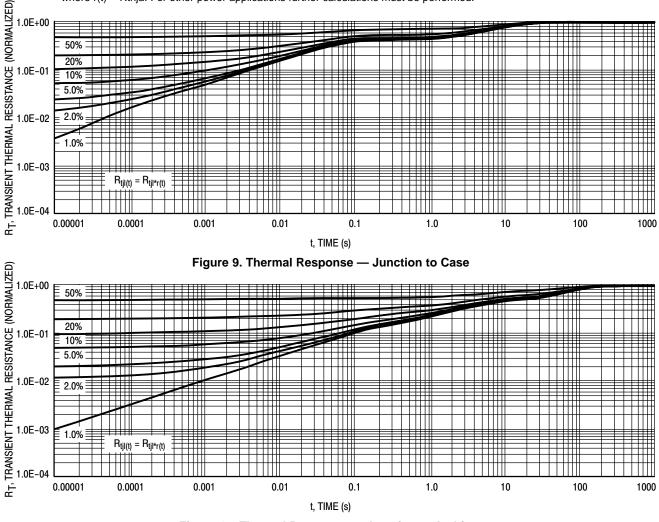
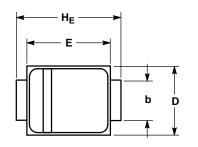
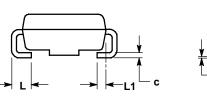


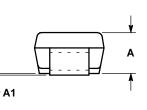
Figure 10. Thermal Response — Junction to Ambient

PACKAGE DIMENSIONS

SMB CASE 403A-03 ISSUE E





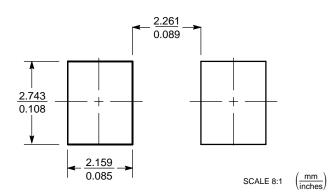


NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.

3. D DIMENSION SHALL BE MEASURED WITHIN DIMENSION P.

	MILLIMETERS			INCHES			
DIM	MIN	NOM	MAX	MIN	NOM	MAX	
Α	1.90	2.13	2.41	0.075	0.084	0.095	
A1	0.05	0.10	0.15	0.002	0.004	0.006	
b	1.96	2.03	2.11	0.077	0.080	0.083	
С	0.15	0.23	0.30	0.006	0.009	0.012	
D	3.30	3.56	3.81	0.130	0.140	0.150	
Е	4.06	4.32	4.57	0.160	0.170	0.180	
HE	5.21	5.44	5.59	0.205	0.214	0.220	
L	0.76	1.02	1.27	0.030	0.040	0.050	
L1	0.51 REF			0.020 REF			

SOLDERING FOOTPRINT*



*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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